



# QPA2628D

## 25 – 31 GHz GaAs Low Noise Amplifier

### Product Overview

Qorvo's QPA2628D is a high-performance, low noise amplifier fabricated on Qorvo's production 90nm pHEMT (QPHT09) process. Covering 25–31 GHz, the QPA2628D provides 22 dB small signal gain and P1dB of 19 dBm, while supporting a noise figure of 1.7 dB and IM3 levels of -53 dBc (at Pout=0 dBm/tone).

The QPA2628D is in die form, 2.40 x 1.00 x 0.10 mm, with both RF ports matched to 50 ohms and with integrated DC blocking caps on both I/O ports for simple system integration.

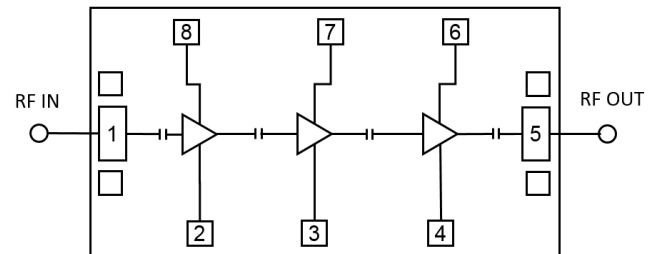
The QPA2628D's high performance and low power consumption make it ideal for satellite and military or commercial radar applications.



### Key Features

- Frequency Range: 25–31 GHz
- Noise Figure: 1.7 dB (typical)
- Small Signal Gain: 22 dB (typical)
- P1dB: 19 dBm (typical)
- IM3: -53 dBc (Pout=0 dBm/tone) (typical)
- Bias:  $V_D = 3.5$  V,  $I_{DQ} = 90$  mA,  $V_G = -0.46$  V (typical)
- Die Dimensions: 2.40 x 1.00 x 0.10 mm

### Functional Block Diagram



### Applications

- Satellite Communications
- Military and Commercial Radar Applications

### Ordering Information

Part No.	Description
QPA2628D	25 – 31 GHz GaAs Low Noise Amplifier
1136447	QPA2628D Evaluation Board

## Absolute Maximum Ratings

Parameter	Rating	Units
Drain Voltage ( $V_D$ )	4.5	V
Drain Current ( $I_{D1}/I_{D2}/I_{D3}$ )	45/45/160	mA
Gate Voltage Range ( $V_G$ )	-1.3 to 0	V
Gate Current ( $I_{G1}/I_{G2}/I_{G3}$ at 125 °C)	5.0/5.0/6.6	mA
RF Input Power (50 $\Omega$ , 85 °C)	20	dBm
Channel Temperature, $T_{CH}$	175	°C
Mounting Temperature (30 seconds)	320	°C
Storage Temperature	-55 to 150	°C

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

## Recommended Operating Conditions

Parameter	Value	Units
Drain Voltage	3.5	V
Drain Current (quiescent, $I_{DQ}$ )	90	mA
Drain Current ( $I_D$ , Low noise / $P_{SAT}$ )	90 / 200	mA
Gate Voltage (typical)	-0.46	V
Operating Temperature Range	-40 to 85	°C

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

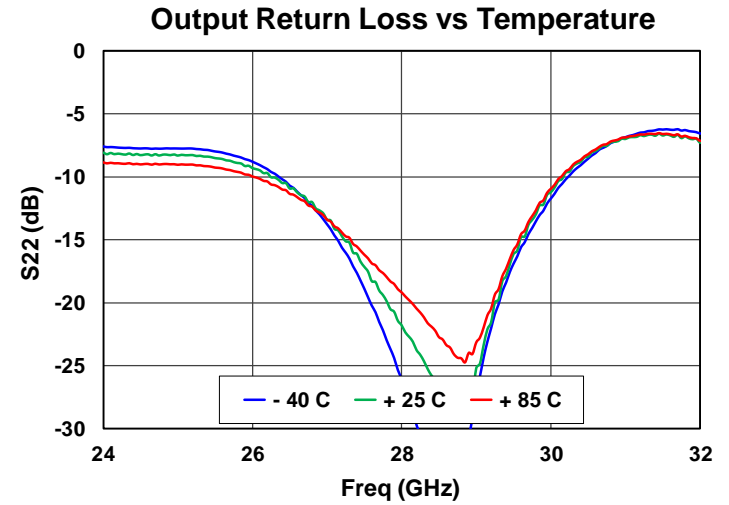
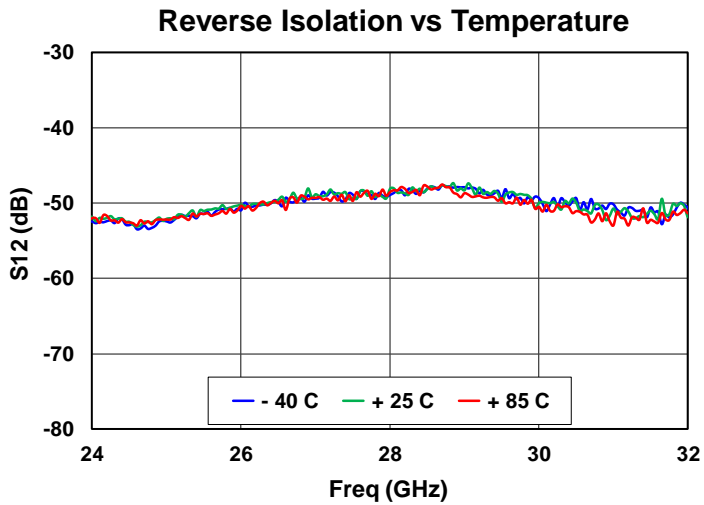
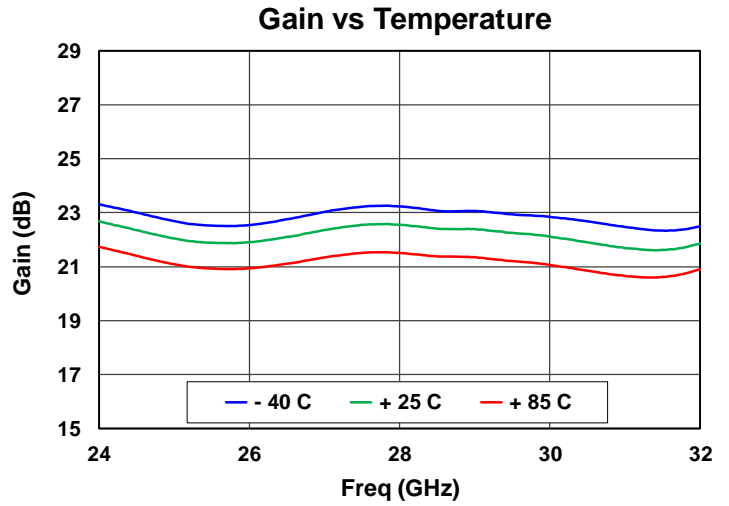
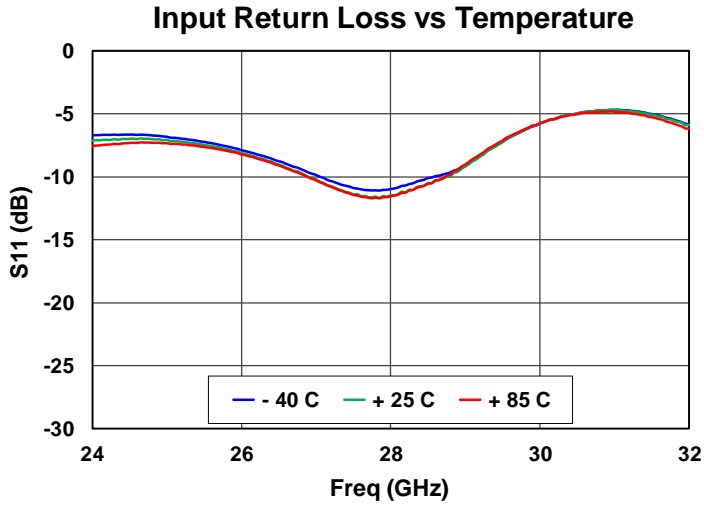
## Electrical Specifications

Test conditions unless otherwise noted:  $V_D = +3.5V$ ,  $I_{DQ} = 90$  mA, Temp. = +25 °C. Data de-embedded to MMIC bond wires.

Parameter	Min	Typ	Max	Units
Operating Frequency	25		31	GHz
Small Signal Gain		22		dB
Noise Figure		1.7		dB
1-dB Compression Point		19		dBm
Input Return Loss		8		dB
Output Return Loss		14		dB
3 <sup>RD</sup> Order Intermodulation Level ( $P_{OUT} = 0$ dBm / Tone)		-53		dBc
Output TOI ( $P_{out} = 0$ dBm / tone)		27		dBm
Gain (S21) Temperature Coefficient		-0.013		dB/°C

## Performance Plots – Small Signal

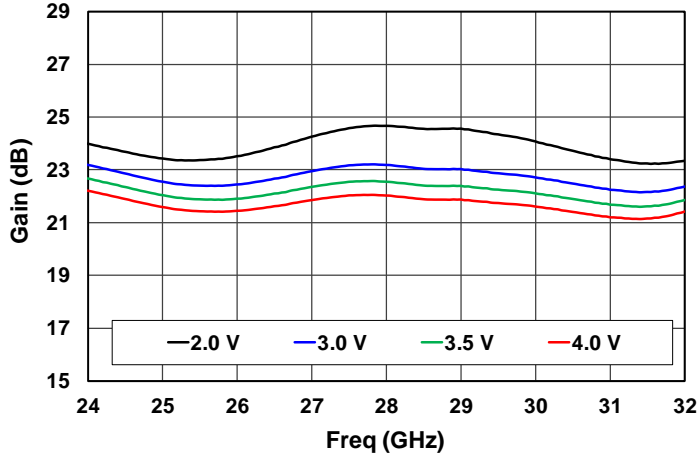
Test conditions unless otherwise noted:  $V_D = +3.5V$ ,  $I_{DQ} = 90\text{ mA}$ , Temp. =  $+25\text{ }^\circ\text{C}$



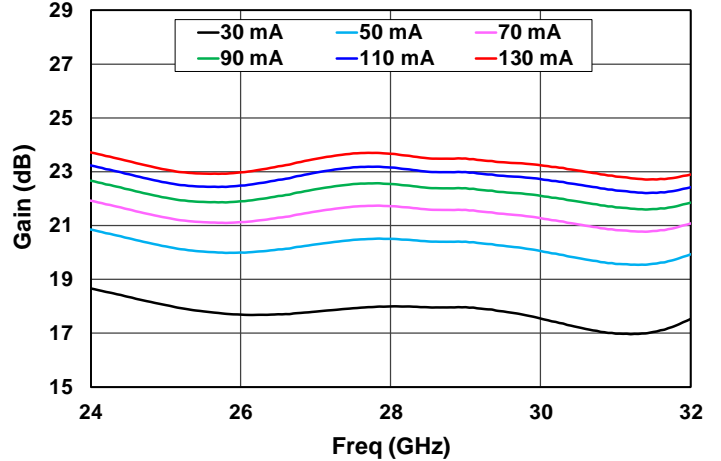
**Performance Plots – Small Signal**

Test conditions unless otherwise noted:  $V_D = +3.5V$ ,  $I_{DQ} = 90\text{ mA}$ ,  $Temp. = +25\text{ }^\circ\text{C}$

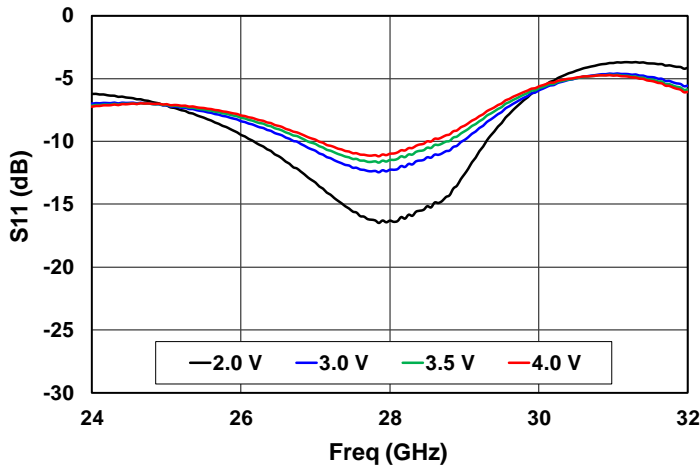
**Gain vs Voltage**



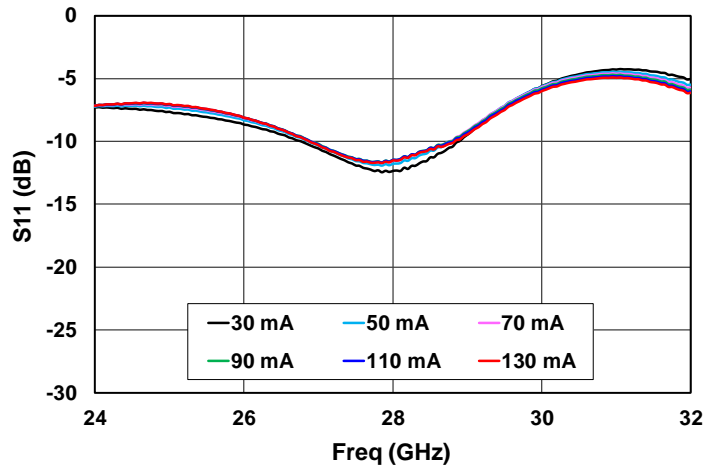
**Gain vs Current**



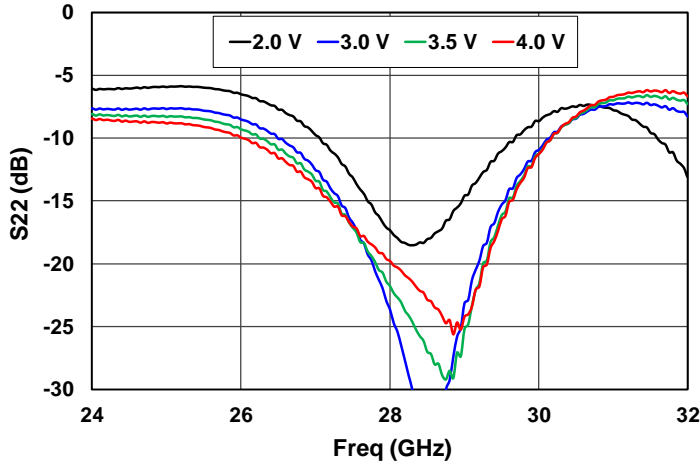
**Input Return Loss vs Voltage**



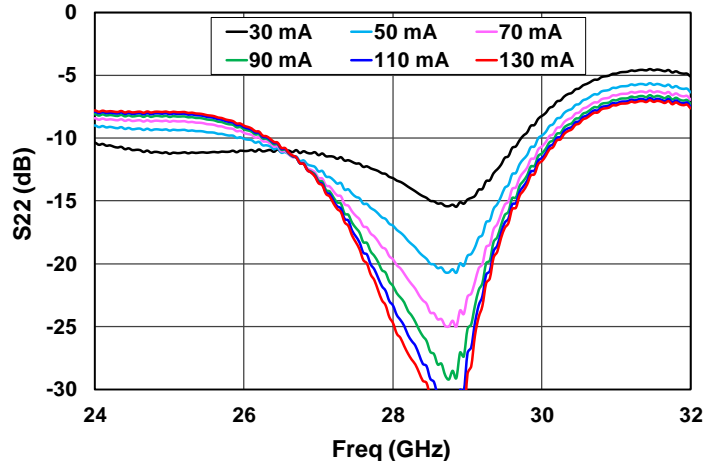
**Input Return Loss vs Current**



**Output Return Loss vs Voltage**



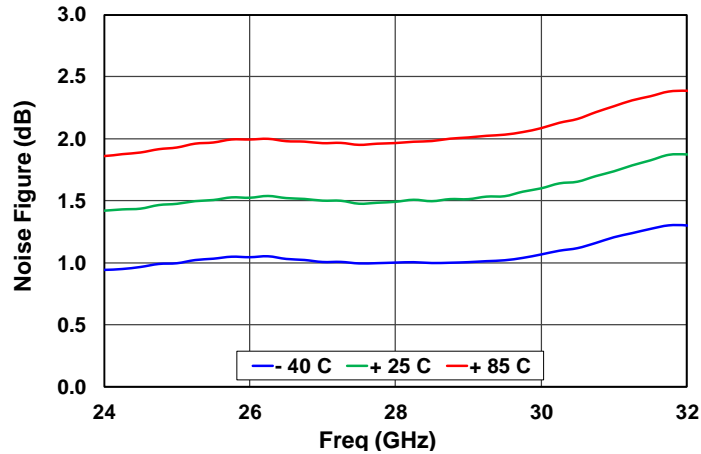
**Output Return Loss vs Current**



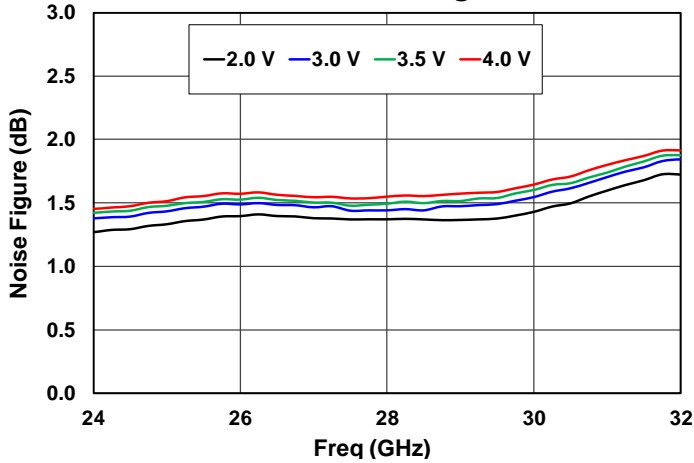
## Performance Plots – Noise Figure

Test conditions unless otherwise noted:  $V_D = +3.5V$ ,  $I_{BQ} = 90\text{ mA}$ , Temp. =  $+25\text{ }^\circ\text{C}$

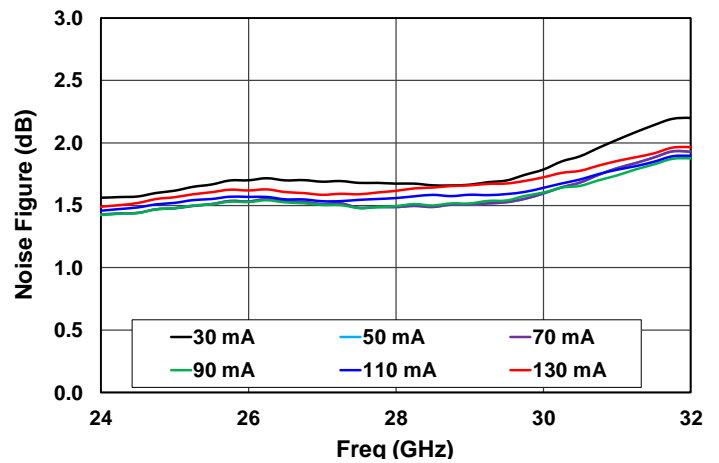
**NF vs Temperature**



**NF vs Voltage**

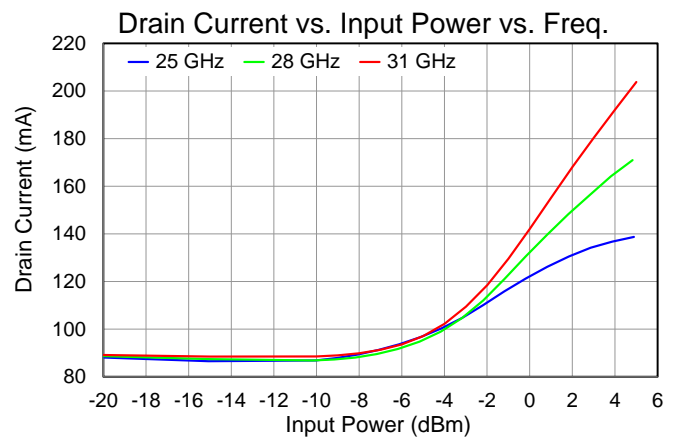
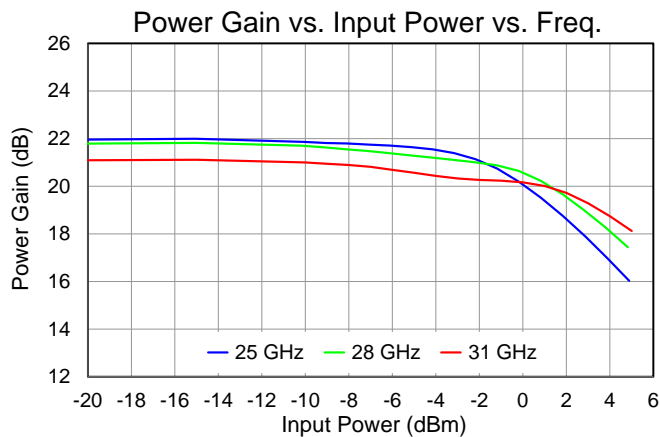
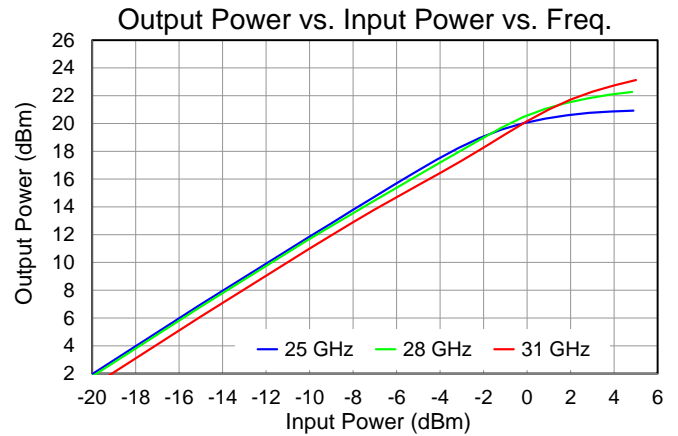
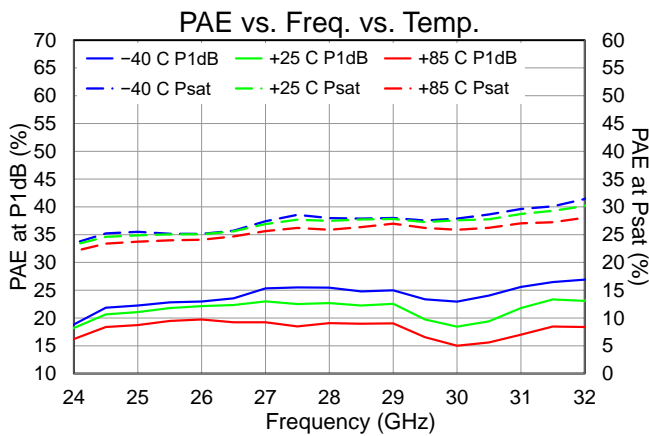
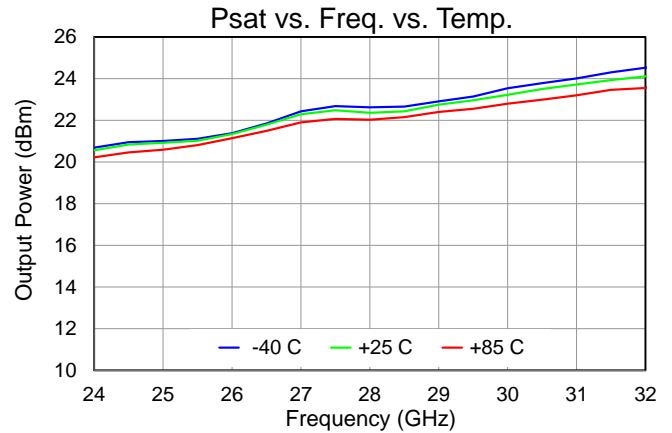
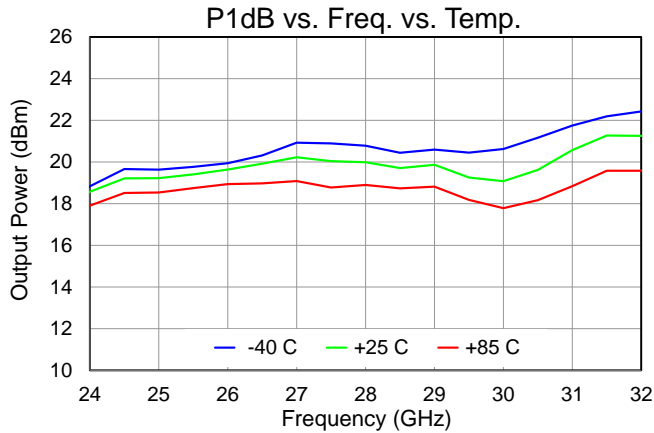


**NF vs Current**



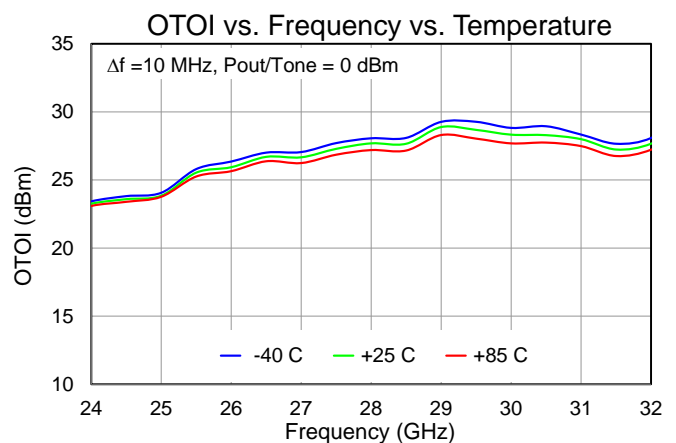
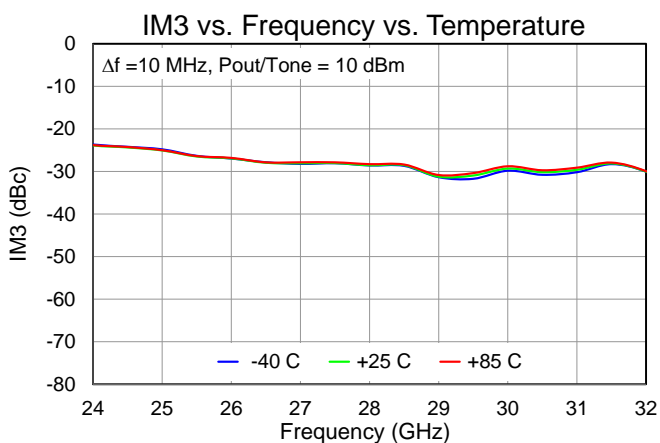
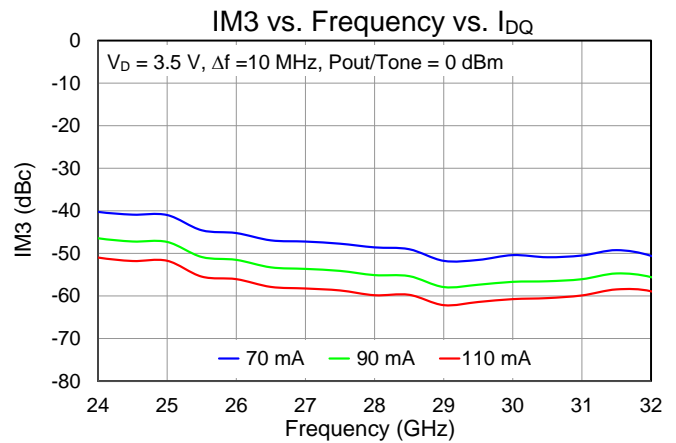
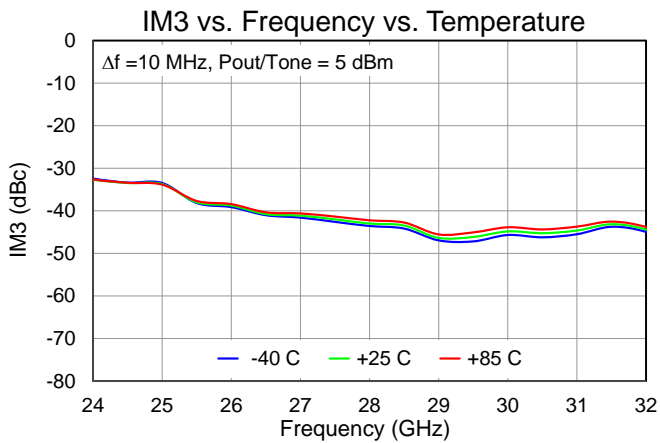
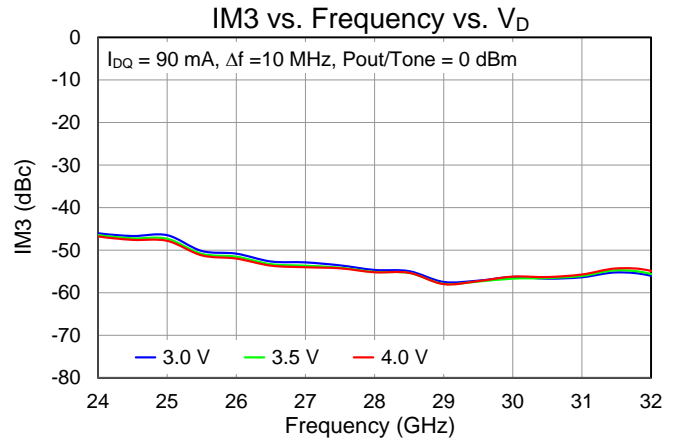
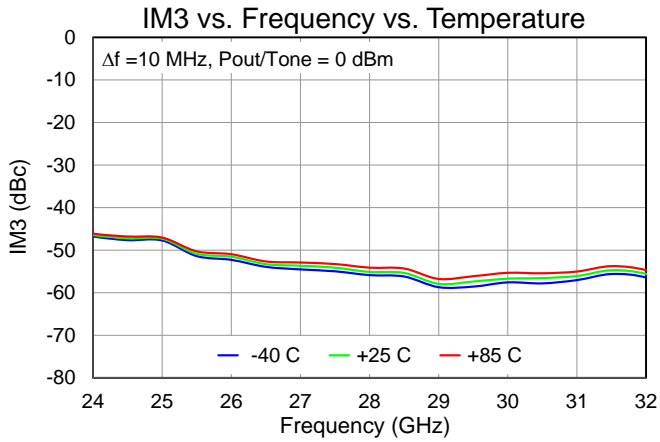
## Performance Plots – Large Signal

Test conditions unless otherwise noted:  $V_D = +3.5V$ ,  $I_{DQ} = 90\text{ mA}$ , Temp. =  $+25^\circ\text{C}$



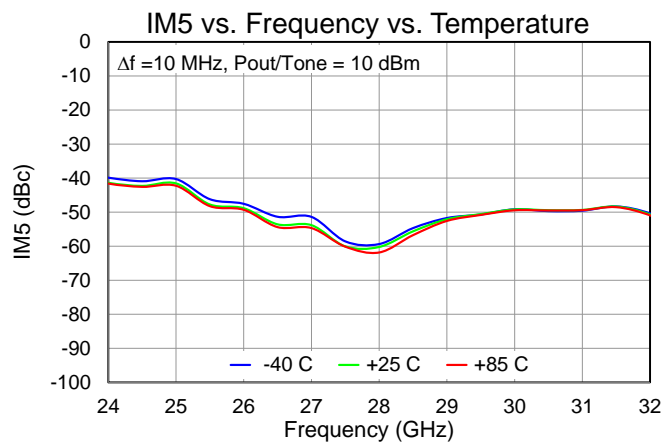
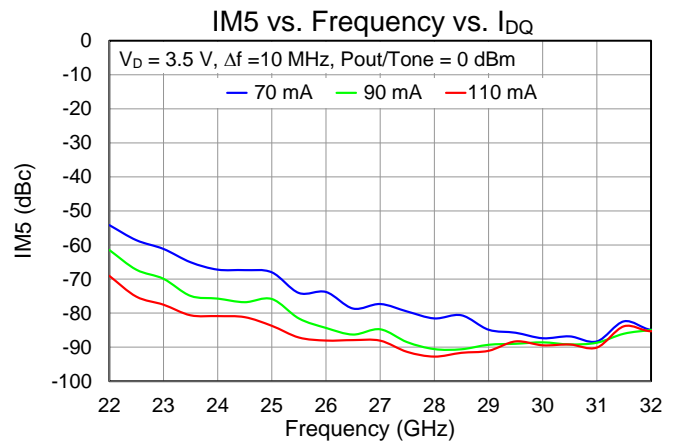
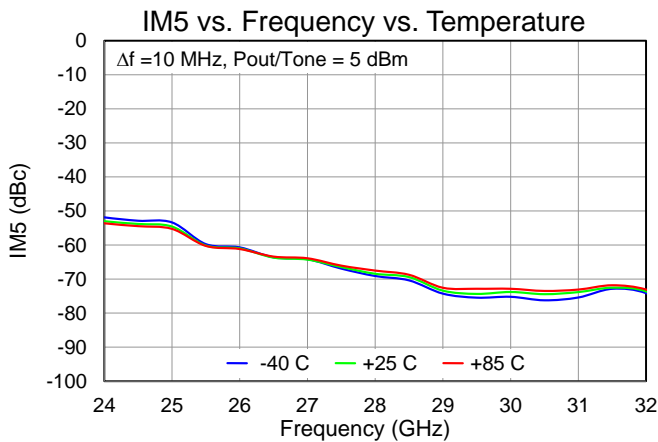
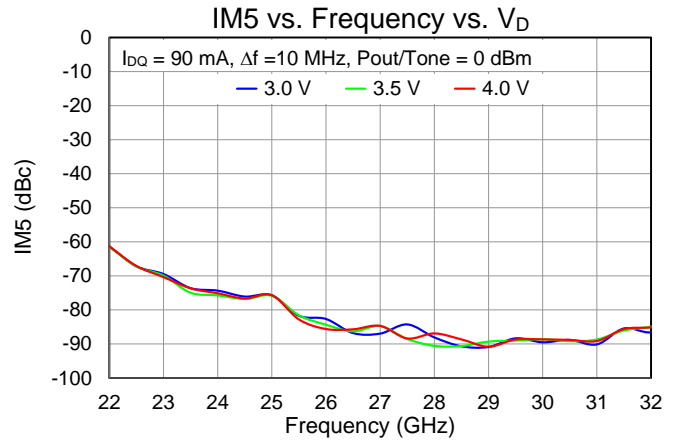
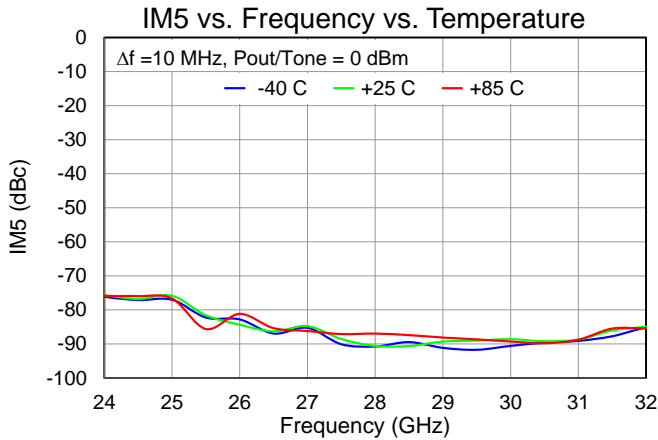
**Performance Plots – Linearity**

Test conditions unless otherwise noted:  $V_D = +3.5V$ ,  $I_{DQ} = 90\text{ mA}$ ,  $25\text{ }^\circ\text{C}$



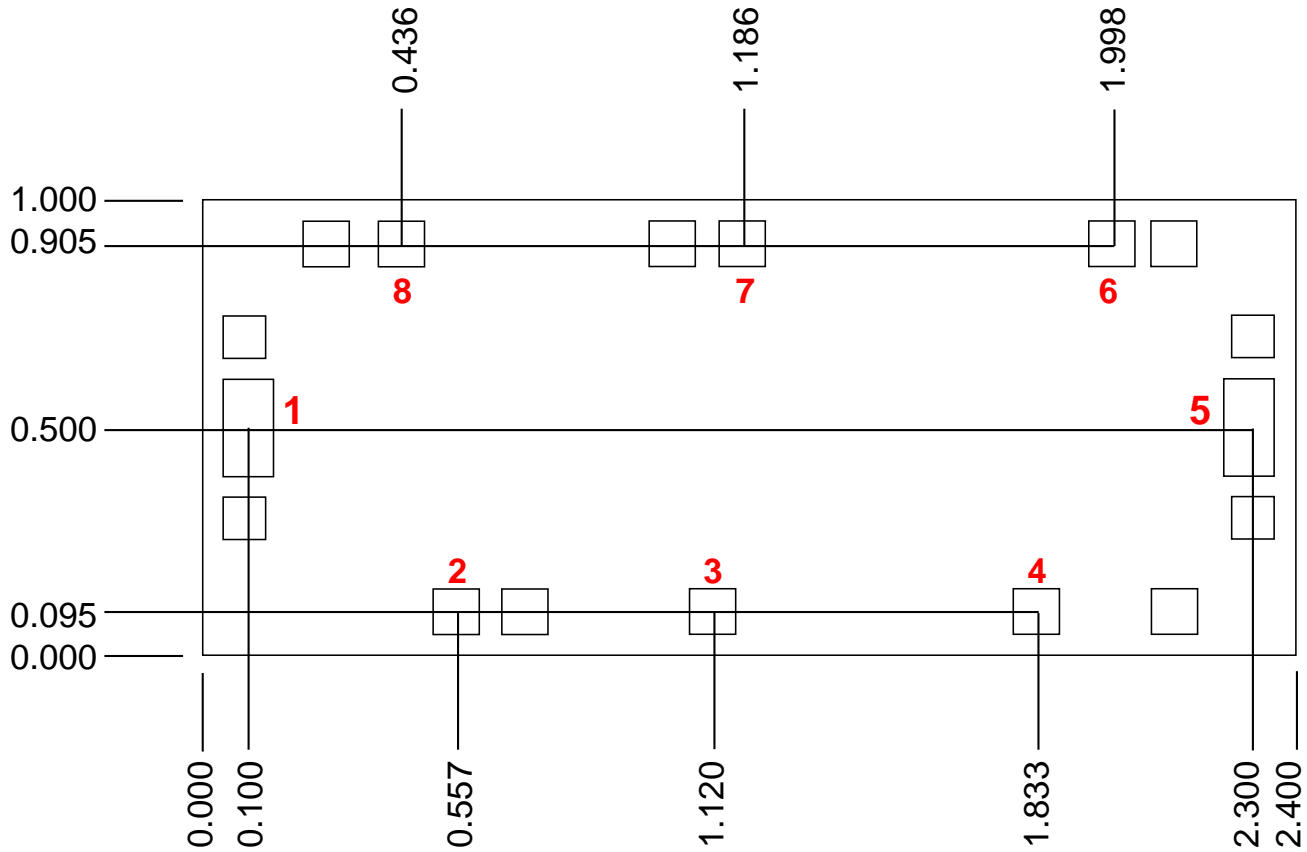
## Performance Plots – Linearity

Test conditions unless otherwise noted:  $V_D = +3.5V$ ,  $I_{DQ} = 90\text{ mA}$ ,  $25\text{ }^\circ\text{C}$





## Mechanical Drawing and Bond Pad Descriptions



Dimensions in mm

Pad No.	Label	Pas Sizes (um)	Description
1	RF Input	91 x 197	Matched to 50 ohms, DC blocked
2	VG1	82 x 82	Gate Voltage; bias network is required ( $V_G$ can be tied together at PCB)
3	VG2	82 x 82	Gate Voltage; bias network is required ( $V_G$ can be tied together at PCB)
4	VG3	82 x 82	Gate Voltage; bias network is required ( $V_G$ can be tied together at PCB)
5	RF Output	91 x 197	Matched to 50 ohms, DC blocked
6	VD3	82 x 82	Drain Voltage; bias network is required ( $V_D$ can be tied together at PCB)
7	VD2	82 x 82	Drain Voltage; bias network is required ( $V_D$ can be tied together at PCB)
8	VD1	82 x 82	Drain Voltage; bias network is required ( $V_D$ can be tied together at PCB)

## Assembly Notes

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Component placement and adhesive attachment assembly notes:

- Vacuum pencils and/or vacuum collets are the preferred method of pick up.
- Air bridges must be avoided during placement.
- The force impact is critical during auto placement.
- Organic attachment (i.e., conductive epoxy) can be used in low-power applications.
- Curing should be done in a convection oven; proper exhaust is a safety concern.

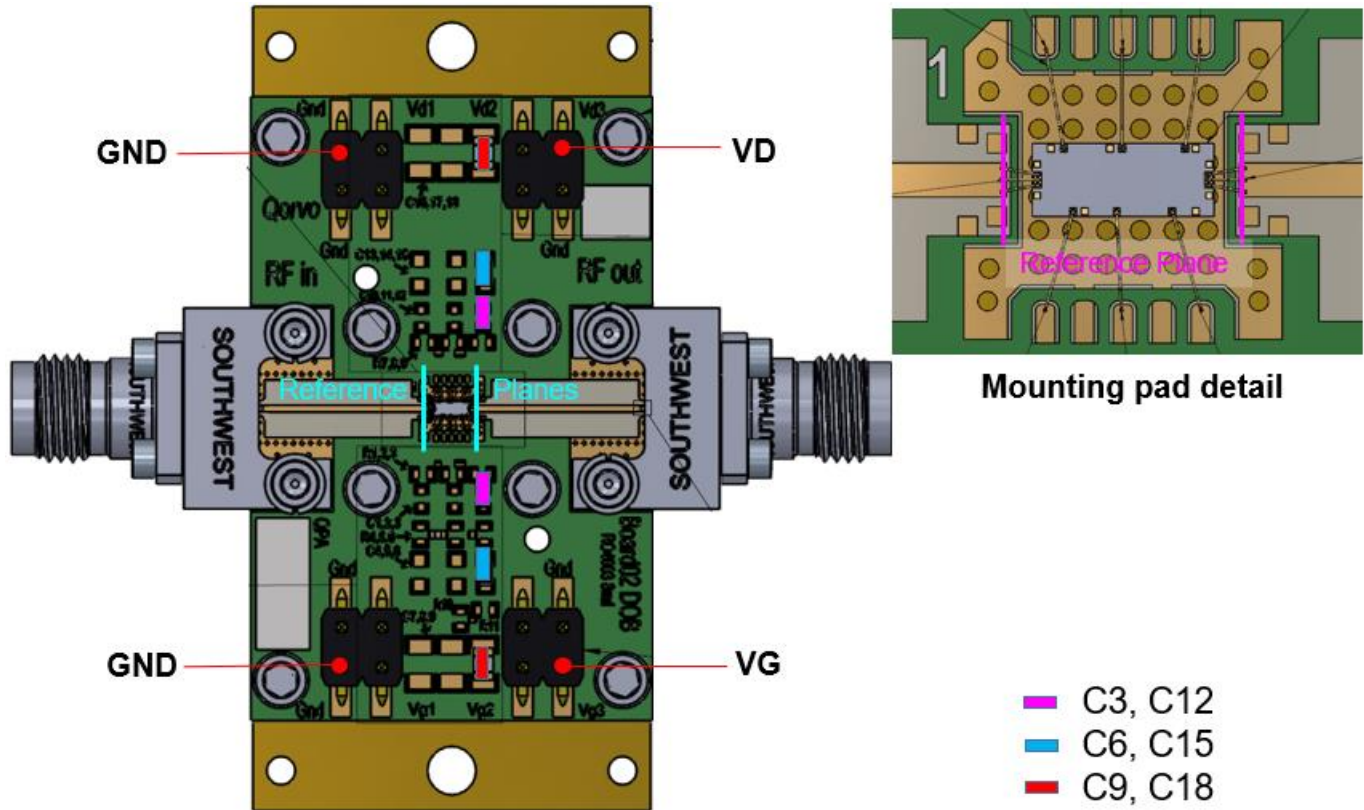
Reflow process assembly notes:

- Use AuSn (80/20) solder and limit exposure to temperatures above 300°C to 3-4 minutes, maximum.
- An alloy station or conveyor furnace with reducing atmosphere should be used.
- Do not use any kind of flux.
- Coefficient of thermal expansion matching is critical for long-term reliability.
- Devices must be stored in a dry nitrogen atmosphere.

Interconnect process assembly notes:

- Thermosonic ball bonding is the preferred interconnect technique.
- Force, time, and ultrasonics are critical parameters.
- Aluminum wire should not be used.
- Devices with small pad sizes should be bonded with 0.0007-inch wire.

Evaluation Board and BOM



RF Layer is 0.008” thick Rogers Corp. RO4003C ( $\epsilon_r = 3.35$ ). Metal layers are 0.5 oz. copper. The microstrip line at the connector interface is optimized for the Southwest Microwave end launch connector 1492-04A-5. PCB level tuning at input side is recommended for optimal performance.

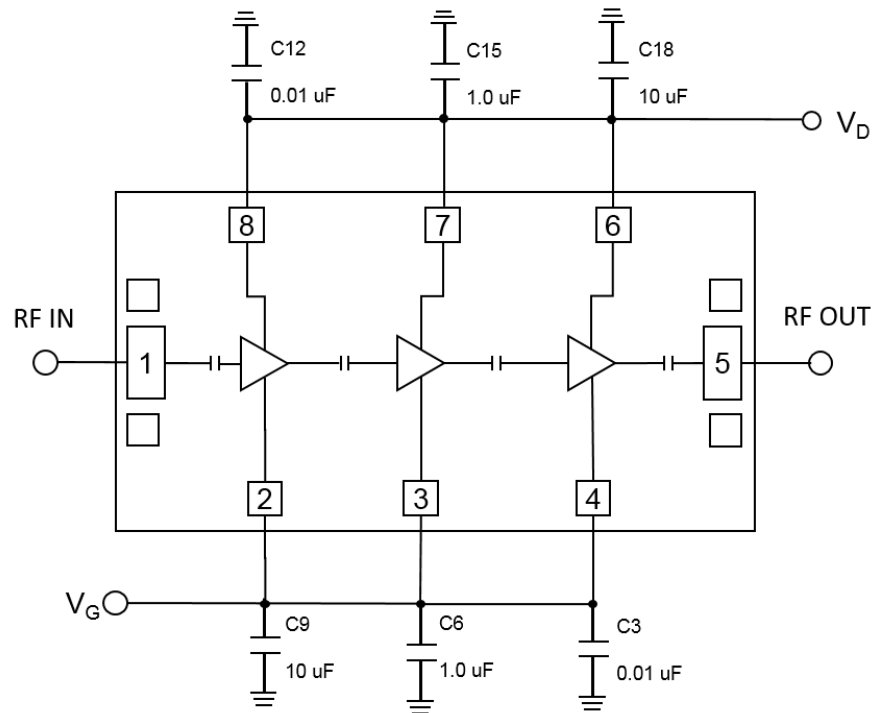
All data de-embedded to the MMIC bondwires (shown).

Note: Multiple vias should be employed under die to minimize inductance and thermal resistance.

Bill of Material – Evaluation Board

Ref. Des.	Value	Description	Manuf.	Part Number
C3, C12	0.01 uF	CAP 0.01uF +/-10% 50V 0402 X7R ROHS	Various	
C6, C15	1.0 uF	CAP 1.0uF +/-10% 16V 0603 X7R ROHS	Various	
C9, C18	10 uF	CAP CER 10uF 10V X7R 10% 0805 TDK ROHS	Various	
RF IN, RF OUT	2.4 mm	2.4 MM END LAUNCH CONNECTOR	Southwest Microwave	1492-04A-5

## Application Circuit



**Notes:**

1. Can use separate gate and drain for individual stage controls.

### Bias-up Procedure

1. Set  $I_D$  limit to 220 mA,  $I_G$  limit to 10 mA
2. Set  $V_G$  to  $-1.3$  V
3. Set  $V_D$  to  $+3.5$  V
4. Adjust  $V_G$  more positive until  $I_{DQ} = 90$  mA  
( $V_G \approx -0.46$  V Typical)
5. Apply RF signal

### Bias-down Procedure

1. Turn off RF signal
2. Reduce  $V_G$  to  $-1.3$  V. Ensure  $I_{DQ} \approx 0$  mA
3. Set  $V_D$  to 0V
4. Turn off  $V_D$  supply
5. Turn off  $V_G$  supply

## Thermal and Reliability Information

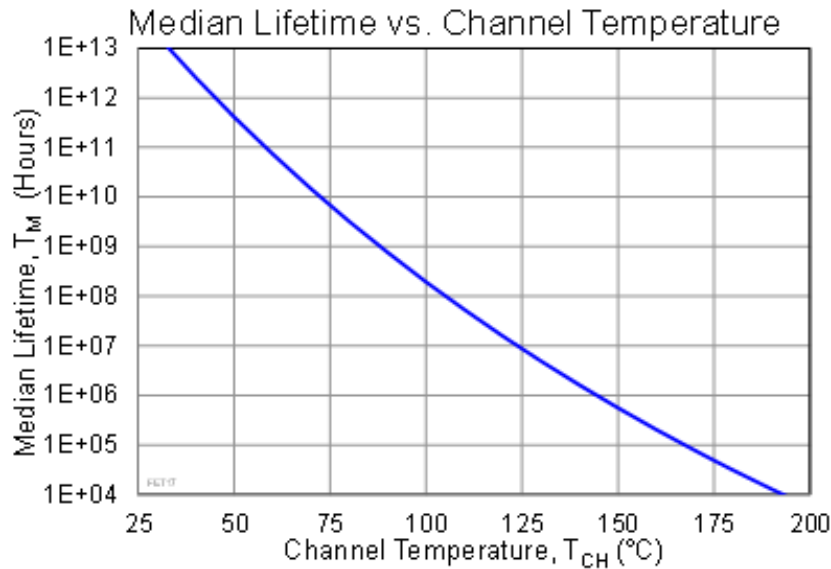
Parameter	Test Conditions	Value	Units
Thermal Resistance ( $\theta_{JC}$ ) <sup>(1)</sup>	$T_{base} = 85^{\circ}\text{C}$ , $V_D = 3.5\text{ V}$ , $I_{DQ} = 90\text{ mA}$ Quiescent/Small Signal operation, $P_{DISS} = 0.315\text{ W}$	65.1	$^{\circ}\text{C}/\text{W}$
Channel Temperature, $T_{CH}$ (Under RF)		105.5	$^{\circ}\text{C}$
Median Lifetime ( $T_M$ )		1.236E08	Hrs

Notes:

- Die mounted to 40 mil CuMo carrier plate with AuSn eutectic. Thermal resistance measured at back of carrier plate.

## Median Lifetime

Test Conditions:  $V_D = +4\text{ V}$   
 Failure Criteria is 10% reduction in  $I_{D\_MAX}$



## Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	1A	ESDA / JEDEC JS-001-2012



Caution!  
ESD-Sensitive Device

## RoHS Compliance

This part is compliant with 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment) as amended by Directive 2015/863/EU.

This product also has the following attributes:

- Lead Free
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A (C<sub>15</sub>H<sub>12</sub>Br<sub>4</sub>O<sub>2</sub>) Free
- SVHC Free

## Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

**Tel: 1-844-890-8163**

**Web: [www.qorvo.com](http://www.qorvo.com)**

**Email: [customer.support@qorvo.com](mailto:customer.support@qorvo.com)**

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